Claim Amendments:

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Currently Amended) A process for producing long lengths of a layered superconductor comprising:
- a. providing a buffered metal substrate tape coated with precursors of REBa₂Cu₃O₇ where RE is a rare earth;
- b. translating the tape through a precursor conversion and film-growth zone in a process chamber;
- c. introducing oxygen and water vapor through a showerhead into the precursor conversion and film growth zone while translating the tape; and
- d. heating the coated substrate tape to a temperature in the range between about 700°C. to about 850°C.;
- where the pressure in the process chamber is in the range between about 1 Torr to about 760 Torr and where the substrate resides in the process-precursor conversion zone for a period of time sufficient to convert the precursors to a superconducting coating epitaxial to the buffer layer.
- 2. (Original) The process of claim 1 where the substrate is selected from the group consisting of stainless steel and nickel alloys.
 - 3. (Original) The process of claim 1 where the substrate is biaxially textured.
- 4. (Original) The process of claim 1 where the buffer on the metal substrate tape is selected from the group consisting of YSZ, CeO₂, MgO, SrTiO₃, LaMnO₃, SrRuO₃, Y₂O₃, Gd₂O₃, LaSrMnO₃ and combinations thereof.
- 5. (Original) The process of claim 1 where the pressure in the process chamber is in the range between about 10 Torr to about 760 Torr.

- 6. (Canceled)
- 7. (Original) The process of claim 1 where the atmosphere in the process chamber has a dew point between about 40°C. to about 80°C.
- 8. (Currently Amended) The process of claim 1 where [[the]] a partial pressure of water vapor in the process chamber is between about 1 Torr and about 50 Torr.
- 9. (Currently Amended) The process claim 1 where portion of the oxygen contained in is introduced through the showerhead with a carrier gas, an oxygen content in the carrier gas ranging [[ranges]] between about 10 ppm and 10%.
- 10. (Currently Amended) The process of claim 1 where [[the]] a partial pressure of the oxygen and water vapor is substantially consistent throughout the precursor conversion and film growth zone.
- 11. (Currently Amended) The process of claim 1 where the distribution of earrier gas eentaining the oxygen and water vapor is uniform throughout the precursor conversion and film growth zone.
 - 12. (Currently Amended) The process of claim 1 wherein the oxygen and water vapor are introduced into the precursor conversion and film growth zone through a A process for producing long lengths of a layered superconductor comprising:
 - a. providing a buffered metal substrate tape coated with precursors of REBa2Cu3O7 where RE is a rare earth;
 - b. translating the tape through a precursor conversion zone in a process chamber;
 - c. introducing oxygen and water vapor through a showerhead into the precursor conversion zone while translating the tape, the showerhead having a width at least as wide as the sum of the widths of the translating tapes plus the sum of the distances between each of the translating tapes and having a length at least as great as the width; and
 - d. heating the to a temperature in the range between about 700°C. to about 850°C.:

- where the pressure in the process chamber is in the range between about 1 Torr to about 760 Torr and where the substrate resides in the precursor conversion zone for a period of time sufficient to convert the precursors to a superconducting coating epitaxial to the buffer layer.
- 13. (Currently Amended) The process of claim 1 wherein reaction by-products are removed from the process chamber by a pumping system located proximate to the precursor conversion and film growth-zone.
- 14. (Original) The process of claim 1 wherein the process chamber is a cold-wall chamber.
- 15. (Currently Amended) The product of the process of claim 1, wherein the showerhead has a plurality of film openings through which the oxygen and water vapor pass.
 - 16. (New) The process of claim 15, wherein the fine openings are evenly spaced.